

DUAL OPERATIONAL AMPLIFIER

■ GENERAL DESCRIPTION

The NJM4565 is a high-gain, wide-bandwidth, dual low noise operational amplifier capable of driving 20V peak-to-peak into 400Ω loads. The NJM4565 is good characteristics compared to the NJM4560.

■ FEATURES

Operating Voltage (±4V~±18V)
 Wide Gain Bandwidth Product (4MHz typ.)
 Slew Rate (4V/µs typ.)

Package Outline
 DIP8, DMP8, SSOP8, SIP8
 SOP8 JEDEC 150mil

Bipolar Technology

■ PACKAGE OUTLINE



NJM4565D (DIP8)



NJM4565M (DMP8)



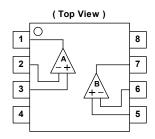
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NJM4565E (SOP8) NJM4565V (SSOP8)

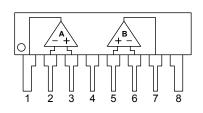


(SIP8)

■ PIN CONFIGURATION



NJM4565D, NJM4565M, NJM4565E, NJM4565V



NJM4565L

PIN FUNCTION

1. A OUTPUT

2. A - INPUT

3. A +INPUT

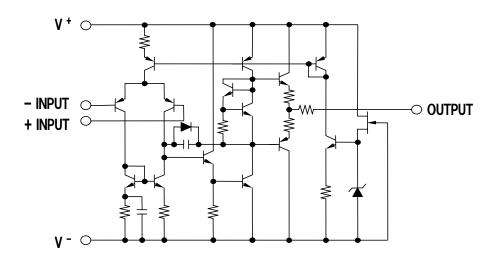
4. V

5. B +INPUT

6. B - INPUT

7. B OUTPUT

■ EQUIVALENT CIRCUIT (1/2 Shown)



■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V⁺∕V⁻	± 18	V
Differential Input Voltage	V_{ID}	± 30	V
Input Voltage	V _{IC}	± 15 (note)	V
Power Dissipation	P _D	(DIP8) 500 (DMP8) 300 (SOP8) 300 (SSOP8) 250 (SIP8) 800	mW
Operating Temperature Range	T _{opr}	-40~+85	°C
Storage Temperature Range	T _{stg}	-40~+125	°C

(note) For supply voltage less than $\pm 15 \text{V}$, the absolute maximum input voltage is equal to the supply voltage.

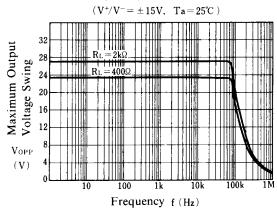
■ ELECTRICAL CHARACTERISTICS

 $(Ta=25^{\circ}C,V^{\dagger}/V=\pm15V)$

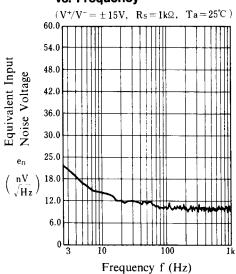
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V _{IO}	R _s ≤10kΩ	-	0.5	3.0	mV
Input Offset Current	I _{IO}		-	2	50	nA
Input Bias Current	I_{B}		-	50	200	nA
Input Resistance	R_{IN}		0.3	5	-	ΜΩ
Large Signal Voltage Gain	A_V	R _L ≥2kΩ,V _O =±10V	86	100	-	dB
Maximum Output Voltage Swing 1	V_{OM1}	R _L ≥2kΩ	± 12	± 14	-	V
Maximum Output Voltage Swing 2	V _{OM2}	I _O =25mA	± 10	± 11.5	-	V
Input Common Mode Voltage Range	V_{ICM}		± 12	± 14	-	V
Common Mode Rejection Ratio	CMR	R _s ≤10kΩ	70	90	-	dB
Supply Voltage Rejection Ratio	SVR	R _S ≤10kΩ	76.5	90	-	dB
Operating Current	Icc		-	4.5	7	mA
Slew Rate	SR		-	4	-	V/µs
Gain Bandwidth Product	GB		-	10	-	MHz
Equivalent Input Noise Voltage	V_{NI}	RIAA, R_s =2.2 $k\Omega$,30 kHz LPF	-	1.2	-	μVrms

■ TYPICAL CHARACTERISTICS

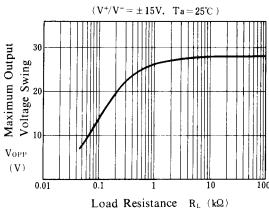
Maximum Output Voltage Swing vs. Frequency



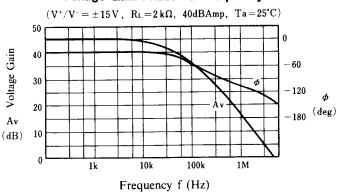
Equivalent Input Noise Voltage vs. Frequency



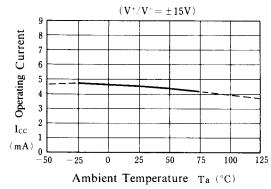
Maximum Output Voltage Swing vs. Load Resistance



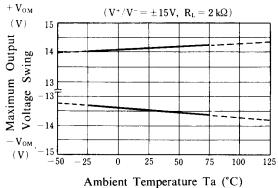
Voltage Gain Phase vs. Frequency



Operating Current vs. Temperature

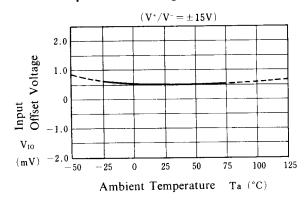


Maximum Output Voltage Swing vs. Temperature

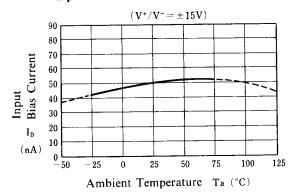


■ TYPICAL CHARACTERISTICS

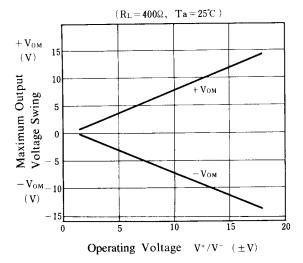
Input Offset Voltage vs. Temperature



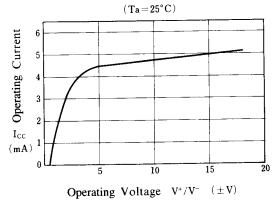
Input Bias Current vs. Temperature



Maximum Output Voltage Swing vs. Operating Voltage



Operating Current vs. Operating Voltage



[CAUTION]
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